NSN 5962-01-253-1555

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dy Length:
90 inches
dy Width:
10 inches
dy Height:
50 inches
ximum Power Dissipation Rating:
watts
erating Tempurature Range:
0/+125.0 degrees celsius
rage Tempurature Range:
.0/+150.0 degrees celsius
tures Provided:
ottky and programmable and bipolar
losure Material:
amic
losure Configuration:
al-in-line
aput Logic Form:
nsistor-transistor logic
ut Circuit Pattern:
nput
se Outline Source And Designator:
mil-m-38510
minal Surface Treatment:
der
tage Rating And Type Per Characteristic:
volts power source
ne Rating Per Chacteristic:
.00 nanoseconds propagation delay time, low to high level output and 100.00 nanoseconds propagation delay time, high to low level
but
mory Device Type:
n
mory Capacity:
nown
at Data Document:
06-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
minal Type And Quantity:
printed circuit
elf Life:
t Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

A458a0

